



LOW DROP POWER SCHOTTKY RECTIFIER

MAIN PRODUCT CHARACTERISTICS

$I_{F(AV)}$	15 A
V_{RRM}	25 V
$T_j(\text{max})$	150 °C
$V_F(\text{max})$	0.35 V

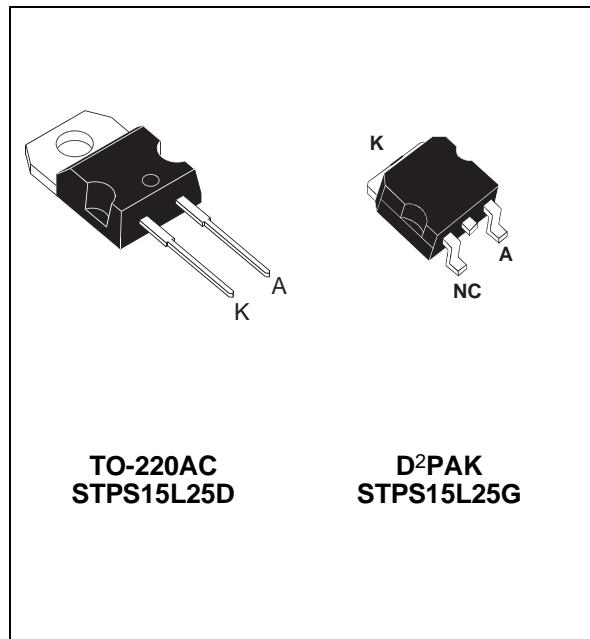
FEATURES

- VERY LOW FORWARD VOLTAGE DROP FOR LESS POWER DISSIPATION AND REDUCED HEATSINK
- OPTIMIZED CONDUCTION/REVERSE LOSSES TRADE-OFF WHICH MEANS THE HIGHEST EFFICIENCY IN THE APPLICATIONS

DESCRIPTION

Single Schottky rectifier suited for Switched Mode Power Supplies and high frequency DC to DC converters (VRMs).

Packaged in TO-220AC or D²PAK, this device is especially intended for use as a Rectifier at the secondary of 3.3V SMPS and DC/DC units.



**TO-220AC
STPS15L25D**

**D²PAK
STPS15L25G**

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
V_{RRM}	Repetitive peak reverse voltage		25	V
$I_{F(RMS)}$	RMS forward current		30	A
$I_{F(AV)}$	Average forward current	$T_c = 145^\circ\text{C} \delta = 0.5$	15	A
I_{FSM}	Surge non repetitive forward current	$t_p = 10\text{ms}$ Sinusoidal	250	A
I_{RRM}	Repetitive peak reverse current	$t_p = 2\mu\text{s}$ square $F = 1\text{kHz}$	1	A
I_{RSM}	Non repetitive peak reverse current	$t_p = 100\mu\text{s}$ square	4	A
T_{stg}	Storage temperature range		- 65 to + 150	°C
T_j	Maximum operating junction temperature *		150	°C
dV/dt	Critical rate of rise of reverse voltage		10000	V/ μs

* : $\frac{dP_{tot}}{dT_j} < \frac{1}{R_{th(j-a)}}$ thermal runaway condition for a diode on its own heatsink

STPS15L25D/G

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
$R_{th(j-c)}$	Junction to case	1	°C/W

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Parameters	Test conditions		Min.	Typ.	Max.	Unit
I_R *	Reverse leakage current	$T_j = 25^\circ\text{C}$	$V_R = V_{RRM}$			1.3	mA
		$T_j = 125^\circ\text{C}$			225	450	mA
V_F *	Forward voltage drop	$T_j = 25^\circ\text{C}$	$I_F = 15\text{A}$			0.46	V
		$T_j = 125^\circ\text{C}$	$I_F = 15\text{A}$		0.3	0.35	
		$T_j = 25^\circ\text{C}$	$I_F = 30\text{A}$			0.56	
		$T_j = 125^\circ\text{C}$	$I_F = 30\text{A}$		0.41	0.46	

Pulse test : * $t_p = 380 \mu\text{s}$, $\delta < 2\%$

To evaluate the maximum conduction losses use the following equation :

$$P = 0.24 \times I_{F(AV)} + 0.0073 I_{F(RMS)}^2$$

Fig.1 : Average forward power dissipation versus average forward current.

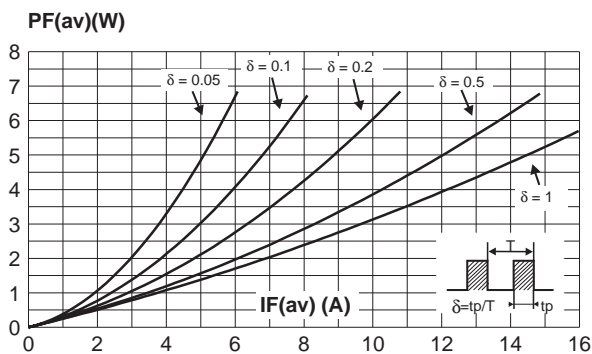


Fig.2 : Average forward current versus ambient temperature ($\delta = 0.5$).

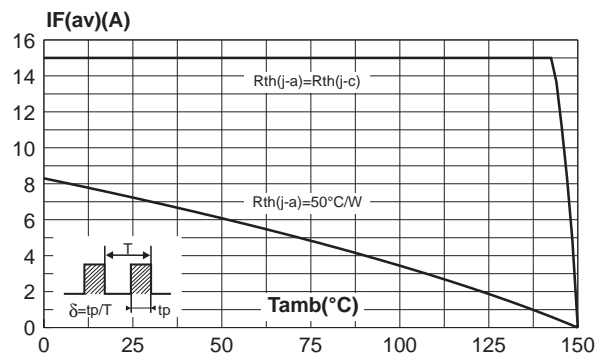


Fig.3 : Non repetitive surge peak forward current versus overload duration (maximum values).

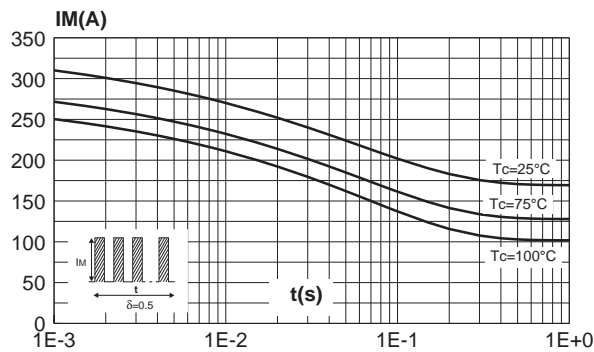


Fig.4 : Relative variation of thermal impedance junction to case versus pulse duration.

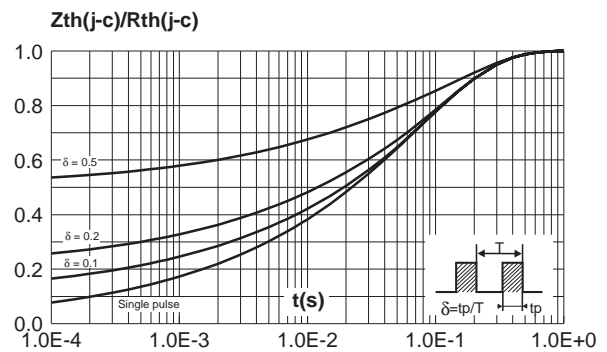


Fig.5 : Reverse leakage current versus reverse voltage applied (typical values).

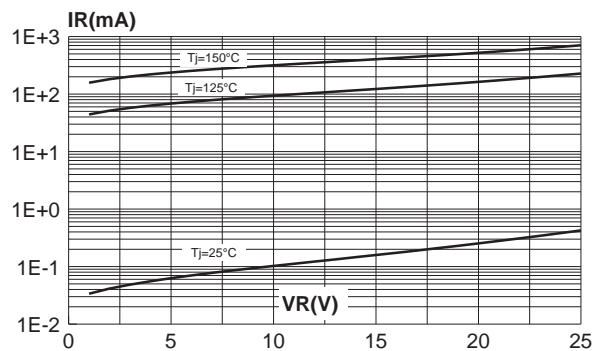


Fig.6 : Junction capacitance versus reverse voltage applied (typical values).

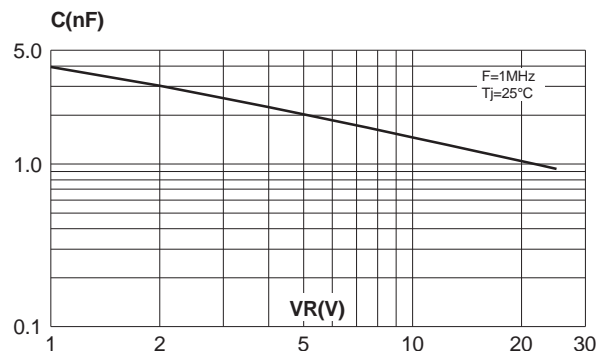


Fig.7 : Forward voltage drop versus forward current (maximum values).

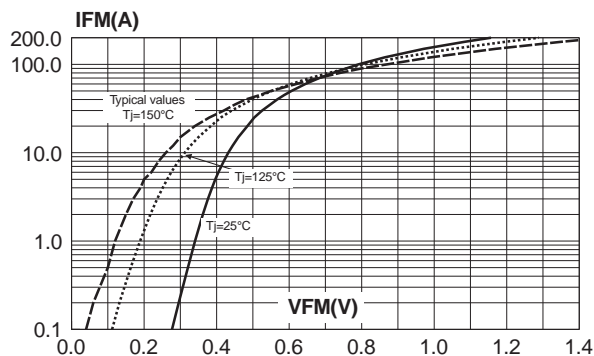
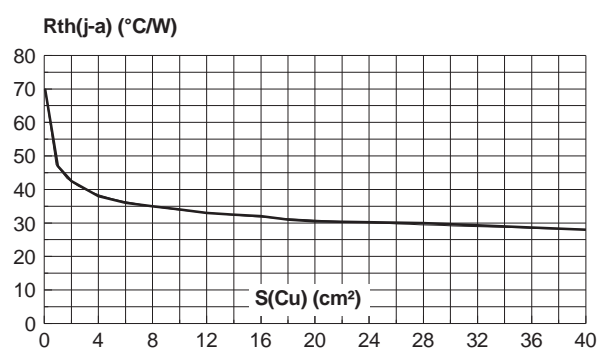
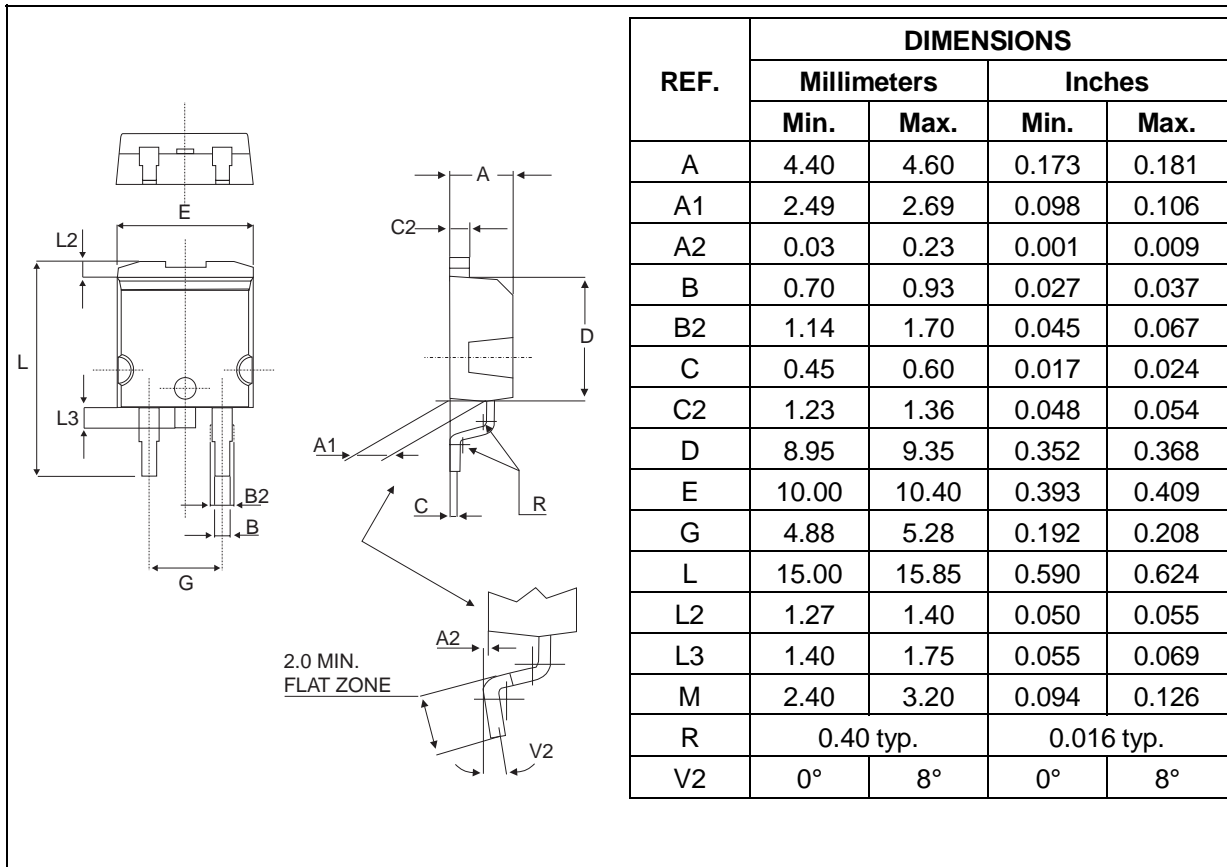


Fig.8 : Thermal resistance junction to ambient versus copper surface under tab (Epoxy printed circuit board FR4, copper thickness : 35 μm). (STPS15L25G only)

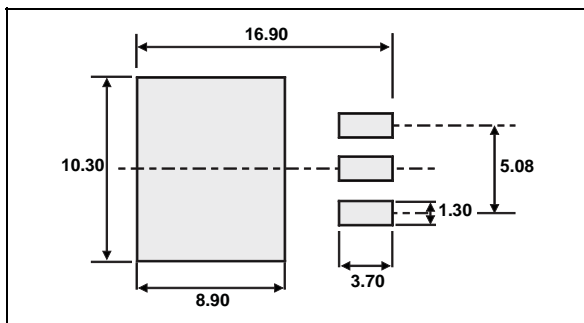


STPS15L25D/G

PACKAGE MECHANICAL DATA D²PAK

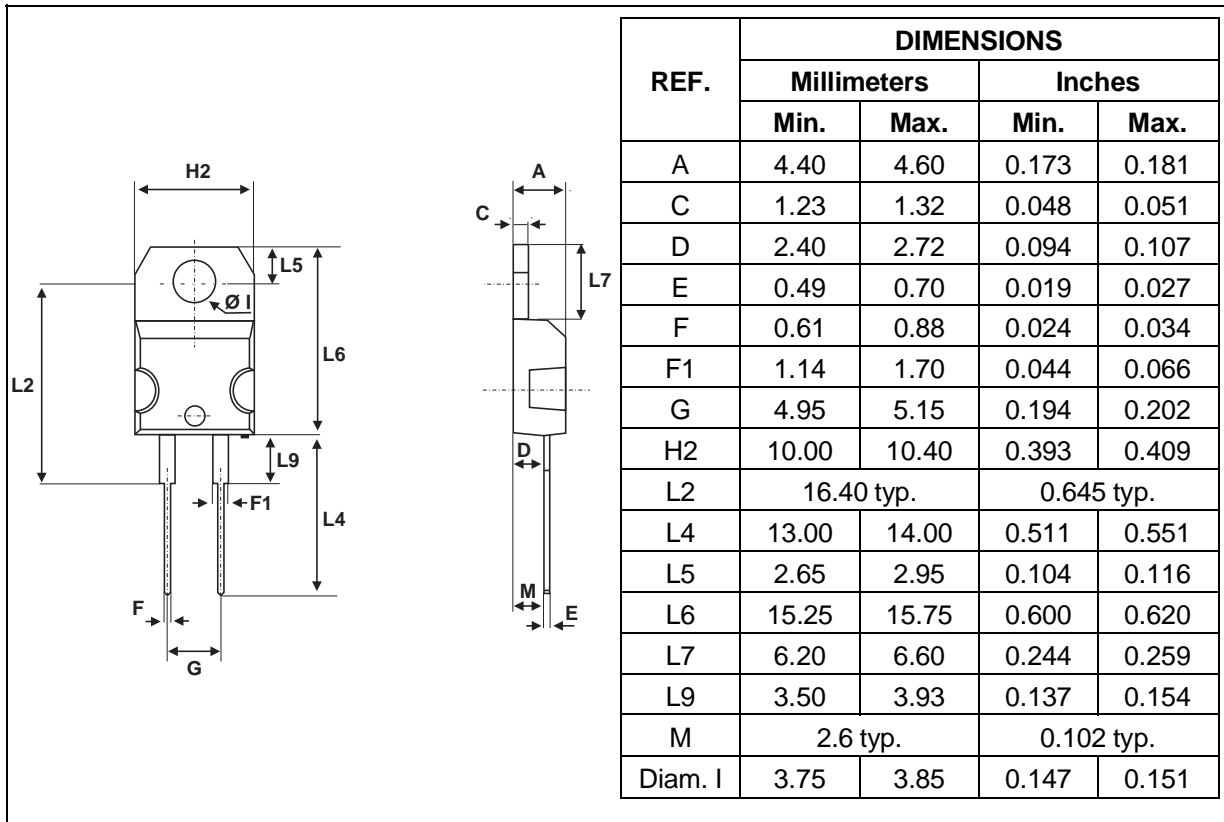


FOOT PRINT DIMENSIONS (in millimeters)



- Cooling method: by conduction (method C)

PACKAGE MECHANICAL DATA
TO-220AC



- Cooling method : C
- Recommended torque value : 0.55 m.N
- Maximum torque value : 0.70 m.N

Ordering type	Marking	Package	Weight	Base qty	Delivery mode
STPS15L25D	STPS15L25D	TO-220AC	1.86g	50	Tube
STPS15L25G	STPS15L25G	D ² PAK	1.48g	50	Tube
STPS15L25G-TR	STPS15L25G	D ² PAK	1.48g	1000	Tape & reel

- Epoxy meets UL94,V0

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